NSN 5961-01-167-5025

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-167-5025 **Inclosure Material:** Metal **Overall Length:** 1.453 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.667 inches and 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 45.0 working peak reverse voltage and 54.0 repetitive peak reverse voltage and 45.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 120.00 amperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: